

Standard Rectifier

$$V_{RRM} = 2 \times 1200 \text{ V}$$

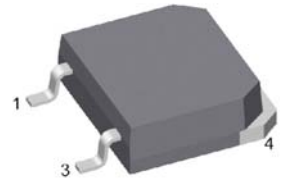
$$I_{FAV} = 45 \text{ A}$$

$$V_F = 1,23 \text{ V}$$

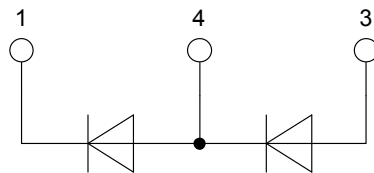
Phase leg

Part number

DSP45-12AZ



Backside: anode/cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour
- High commutation robustness
- High surge capability

Applications:

- Diode for main rectification
- For single and three phase bridge configurations

Package: TO-268AA (D3Pak-HV)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

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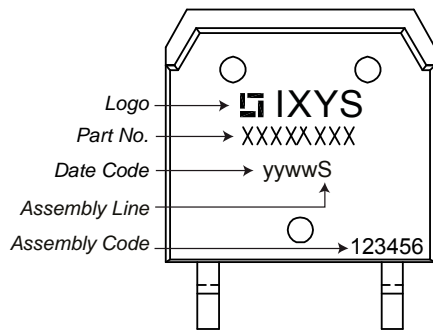


Rectifier			Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			1300	V	
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			1200	V	
I_R	reverse current	$V_R = 1200 V$			40	μA	
		$V_R = 1200 V$			1,5	mA	
V_F	forward voltage drop	$I_F = 45 A$			1,26	V	
		$I_F = 90 A$			1,52	V	
		$I_F = 45 A$	$T_{VJ} = 150^{\circ}C$			1,23	V
		$I_F = 90 A$	$T_{VJ} = 150^{\circ}C$			1,57	V
I_{FAV}	average forward current	$T_C = 130^{\circ}C$ 180° sine			45	A	
V_{F0}	threshold voltage	} for power loss calculation only			0,86	V	
r_F	slope resistance				7,8	m Ω	
R_{thJC}	thermal resistance junction to case				0,55	K/W	
R_{thCH}	thermal resistance case to heatsink			0,15		K/W	
P_{tot}	total power dissipation	$T_C = 25^{\circ}C$			270	W	
I_{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$		480	A	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$		520	A	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150^{\circ}C$		410	A	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$		440	A	
I^2t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$		1,15	kA ² s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$		1,13	kA ² s	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150^{\circ}C$		840	A ² s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$		805	A ² s	
C_J	junction capacitance	$V_R = 400 V; f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		19	pF	



Package TO-268AA (D3Pak-HV)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			70	A
T_{VJ}	virtual junction temperature		-40		175	°C
T_{op}	operation temperature		-40		150	°C
T_{stg}	storage temperature		-40		150	°C
Weight				4		g
F_C	mounting force with clip		20		120	N
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	9,4			mm
$d_{Spb/Apb}$		terminal to backside	5,6			mm

Product Marking



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSP45-12AZ-TUB	DSP45-12AZ-TUB	Tube	30	514134
Alternative	DSP45-12AZ-TRL	DSP45-12AZ	Tape & Reel	400	524061

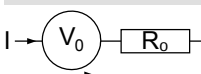
Similar Part	Package	Voltage class
DSP45-16AZ	TO-268AA (D3Pak) (2HV)	1600
DSP45-12A	TO-247AD (3)	1200
DSP45-16A	TO-247AD (3)	1600
DSP45-16AR	ISOPLUS247 (3)	1600

DSP45-18A	TO-247AD (3)	1800
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Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 175^{\circ}C$

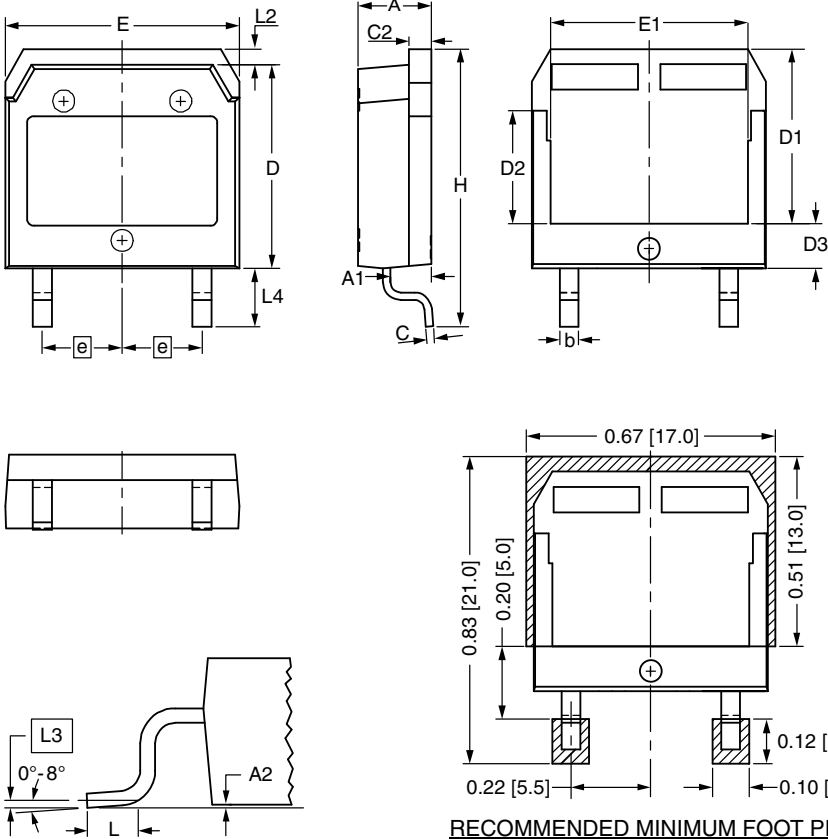


Rectifier

$V_{0\ max}$	threshold voltage	0,86	V
$R_{0\ max}$	slope resistance *	6,5	mΩ

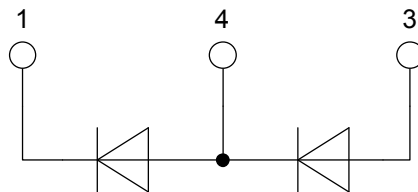


Outlines TO-268AA (D3Pak-HV)



RECOMMENDED MINIMUM FOOT PRINT

Dim.	Millimeter		Inches	
	min	max	min	max
A	4.90	5.10	0.193	0.201
A1	2.70	2.90	0.106	0.114
A2	0.02	0.25	0.001	0.010
b	1.15	1.45	0.045	0.057
C	0.40	0.65	0.016	0.026
C2	1.45	1.60	0.057	0.063
D	13.80	14.00	0.543	0.551
D1	11.80	12.10	0.465	0.476
D2	7.50	7.80	0.295	0.307
D3	2.90	3.20	0.114	0.126
E	15.85	16.05	0.624	0.632
E1	13.30	13.60	0.524	0.535
e	5.450 BSC		0.215 BSC	
H	18.70	19.10	0.736	0.752
L	1.70	2.00	0.067	0.079
L2	1.00	1.15	0.039	0.045
L3	0.250 BSC		0.010 BSC	
L4	3.80	4.10	0.150	0.161



Rectifier

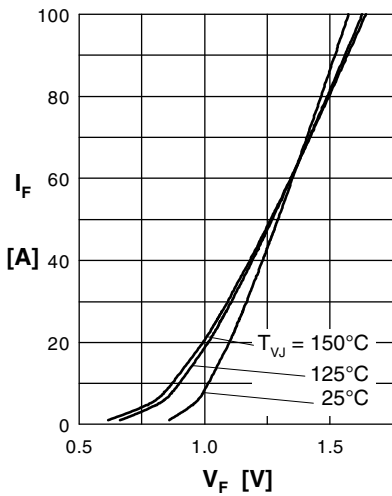


Fig. 1 Forward current versus voltage drop per diode

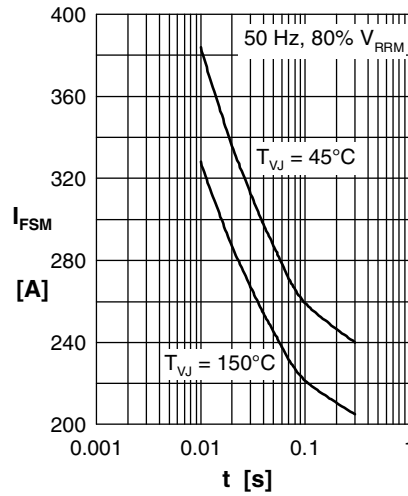


Fig. 2 Surge overload current

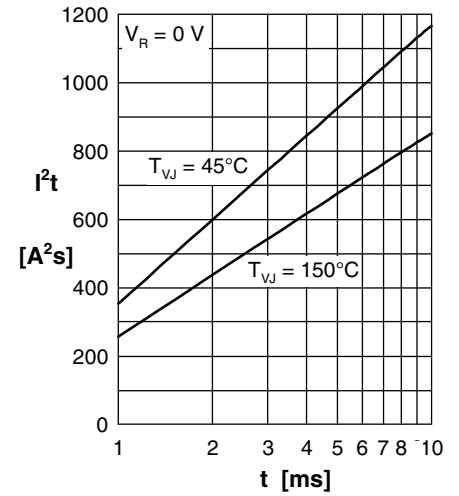


Fig. 3 I^2t versus time per diode

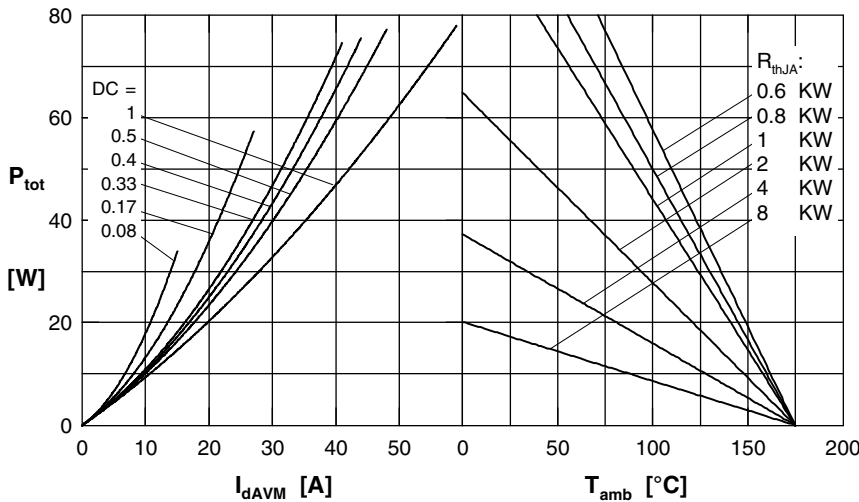


Fig. 4 Power dissipation vs. direct output current & ambient temperature

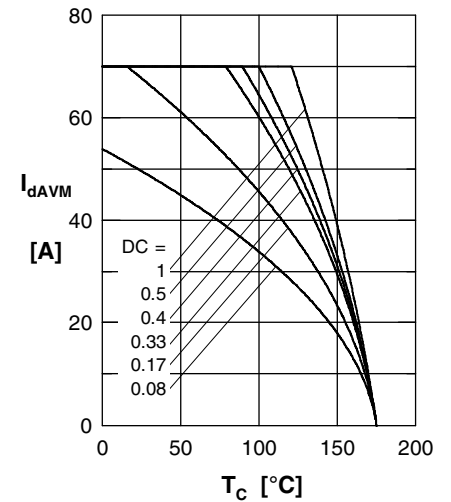


Fig. 5 Max. forward current vs. case temperature

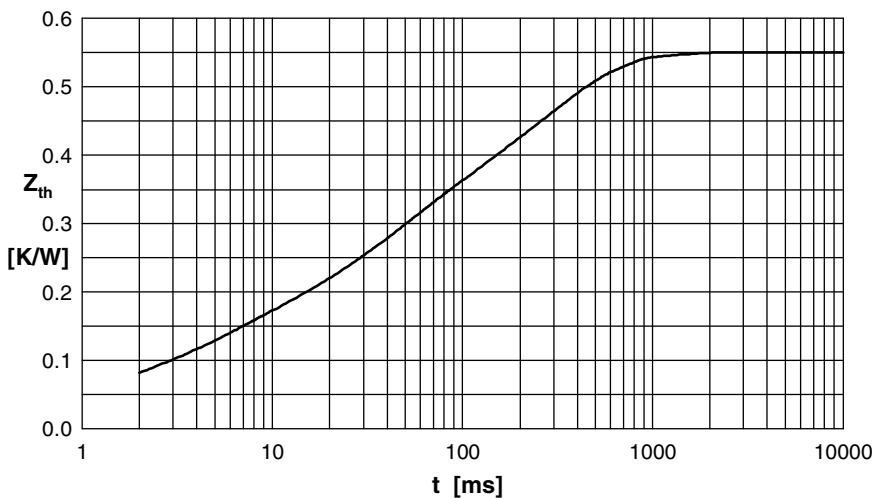


Fig. 6 Transient thermal impedance junction to case

i	R_i	t_i
1	0.033	0.0006
2	0.095	0.0039
3	0.164	0.033
4	0.258	0.272